SPL PL90_3

Radial T1 3/4

Nanostack Pulsed Laser Diode in Plastic Package 75 W Peak Power







Applications

- Electronic Equipment
- Equipment Illumination (e.g. Curing, Endoscope)
- Highbay Industrial

- Industrial Automation (Machine Controls, Light Barriers, Vision Controls)
- Safety and Security, CCTV

Features:

- Laser wavelength 905 nm
- Suited for short laser pulses from 1 to 100 ns
- Nanostack laser technology including 3 epitaxially stacked emitters
- Laser aperture 200 μm x 10 μm
- Cost effective plastic package for high volume applications

Ordering Information

| Туре | Peak output power | Ordering Code |
|------|--|---------------|
| | typ. $I_F = 30 \text{ A}$; $t_D = 100 \text{ ns}$; $f = 1 \text{ kHz}$; $T_A = 25 \text{ °C}$ | |
| | P_{opt} | |

SPL PL90_3 75 W Q62702P5353



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Maximum Ratings

short time operation, T_A = 25 °C

| Parameter | Symbol | | Values |
|---------------------------------|------------------|------|--------|
| Operating Temperature | T _{op} | min. | -40 °C |
| | op | max. | 85 °C |
| Storage Temperature | T _{stg} | min. | -40 °C |
| | 3.9 | max. | 100 °C |
| Peak output power | P _{opt} | max. | 90 W |
| Forward current | I _F | max. | 40 A |
| Pulse width (FWHM) | t _P | max. | 100 ns |
| Duty cycle | dc | max. | 0.1 % |
| Reverse voltage | V_R | max. | 3 V |
| Soldering temperature | T _s | max. | 260 °C |
| (2 mm from bottom edge of case) | Ü | | |

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Characteristics

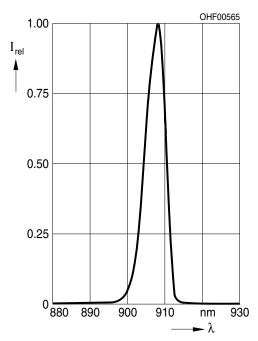
 $I_{_{\rm F}}$ = 30 A; $t_{_{\rm p}}$ = 100 ns; f = 1 kHz; $T_{_{\rm A}}$ = 25 °C

| Parameter | Symbol | | Values |
|---|----------------------|------|--------------|
| Number of emitters | n | typ. | 3 |
| Operating voltage | V _{op} | min. | 8 V |
| | S.P. | typ. | 9 V |
| | | max. | 11 V |
| Peak Wavelength | λ_{peak} | min. | 895 nm |
| | , | typ. | 905 nm |
| | | max. | 915 nm |
| Spectral Bandwidth at 50% I _{rel,max} | Δλ | typ. | 7 nm |
| Peak output power | P_{opt} | min. | 65 W |
| | | typ. | 75 W |
| | | max. | 85 W |
| Beam divergence (FWHM) parallel to pn-junction | Θ_{\parallel} | typ. | 9 ° |
| Beam divergence (FWHM) perpendicular to pn-junction | Θ_{\perp} | typ. | 25 ° |
| Threshold current | I _{th} | min. | 0.5 A |
| | | typ. | 0.75 A |
| | | max. | 1 A |
| Rise time | t _r | typ. | 1 ns |
| Fall time | t _f | typ. | 1 ns |
| Aperture size | wxh | typ. | 200 X 10 μm² |
| Temperature coefficient of wavelength | TC _λ | typ. | 0.28 nm / K |
| Temperature coefficient of optical power | TC _P | typ. | -0.4 % / K |
| Thermal resistance junction ambient real | R_{thJA} | typ. | 160 K / W |
| | | | |



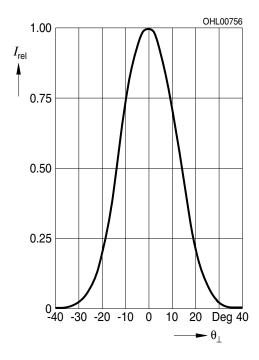
Relative Spectral Emission 1), 2)

$$I_{rel} = f(\lambda); I_F = 30 \text{ A}; P_{opt} = 75 \text{ W}; t_p = 100 \text{ ns}$$



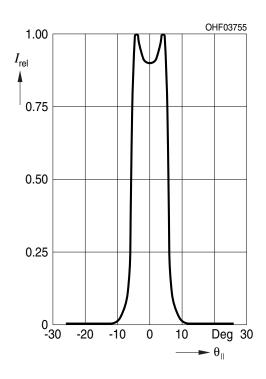
Far-Field Distribution Perpendicular to pn-Junction 1), 2)

$$I_{rel} = f(\Theta_{\perp}); P_{opt} = 75 \text{ W}$$



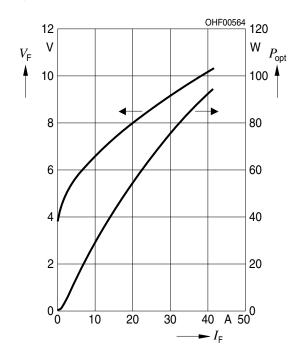
Far-Field Distribution Parallel to pn-Junction 1), 2)

$$I_{rel} = f(\Theta_{II}); P_{opt} = 75 \text{ W}$$

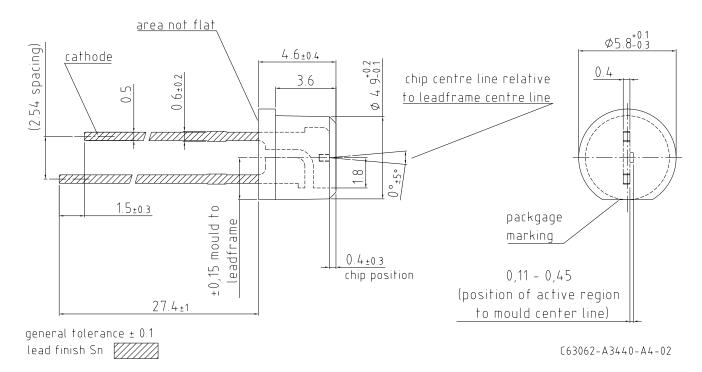


Opt. Power / Forward Voltage 1), 2)

$$P_{opt}$$
, $V_F = f(I_F)$



Dimensional Drawing 3)



Approximate Weight: 241.0 mg

Package marking: Anode

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

For further application related informations please visit www.osram-os.com/appnotes



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Glossary

- Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Testing temperature: $T_A = 25$ °C
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



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